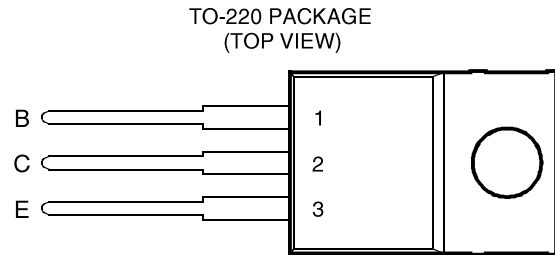


- 40 W at 25°C Case Temperature
- 1 A Continuous Collector Current
- 2 A Peak Collector Current
- 20 mJ Reverse-Energy Rating



Pin 2 is in electrical contact with the mounting base.

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage ( $I_E = 0$ )	TIP47	$V_{CBO}$	350	V
	TIP48		400	
	TIP49		450	
	TIP50		500	
Collector-emitter voltage ( $I_B = 0$ )	TIP47	$V_{CEO}$	250	V
	TIP48		300	
	TIP49		350	
	TIP50		400	
Emitter-base voltage		$V_{EBO}$	5	V
Continuous collector current		$I_C$	1	A
Peak collector current (see Note 1)		$I_{CM}$	2	A
Continuous base current		$I_B$	0.6	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)		$P_{tot}$	40	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)		$P_{tot}$	2	W
Unclamped inductive load energy (see Note 4)		$\frac{1}{2}LI_C^2$	20	mJ
Operating junction temperature range		$T_j$	-65 to +150	°C
Storage temperature range		$T_{stg}$	-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds		$T_L$	260	°C

- NOTE
- 1: This value applies for  $t_p \leq 1$  ms, duty cycle  $\leq 2\%$ .
  - 2: Derate linearly to 150°C case temperature at the rate of 0.32 W/°C.
  - 3: Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
  - 4: This rating is based on the capability of the transistor to operate safely in a circuit of:  $L = 20$  mH,  $I_{B(on)} = 0.4$  A,  $R_{BE} = 100 \Omega$ ,  $V_{BE(off)} = 0$ ,  $R_S = 0.1 \Omega$ ,  $V_{CC} = 20$  V.

# TIP47, TIP48, TIP49, TIP50 NPN SILICON POWER TRANSISTORS

## electrical characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$ Collector-emitter breakdown voltage	$I_C = 30 \text{ mA}$ (see Note 5)	$I_B = 0$	TIP47 TIP48 TIP49 TIP50	250 300 350 400			V
$I_{CES}$ Collector-emitter cut-off current	$V_{CE} = 350 \text{ V}$ $V_{CE} = 400 \text{ V}$ $V_{CE} = 450 \text{ V}$ $V_{CE} = 500 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	TIP47 TIP48 TIP49 TIP50			1 1 1 1	mA
$I_{CEO}$ Collector cut-off current	$V_{CE} = 150 \text{ V}$ $V_{CE} = 200 \text{ V}$ $V_{CE} = 250 \text{ V}$ $V_{CE} = 300 \text{ V}$	$I_B = 0$ $I_B = 0$ $I_B = 0$ $I_B = 0$	TIP47 TIP48 TIP49 TIP50			1 1 1 1	mA
$I_{EBO}$ Emitter cut-off current	$V_{EB} = 5 \text{ V}$	$I_C = 0$				1	mA
$h_{FE}$ Forward current transfer ratio	$V_{CE} = 10 \text{ V}$ $V_{CE} = 10 \text{ V}$	$I_C = 0.3 \text{ A}$ $I_C = 1 \text{ A}$	(see Notes 5 and 6)	30 10		150	
$V_{CE(sat)}$ Collector-emitter saturation voltage	$I_B = 0.2 \text{ A}$	$I_C = 1 \text{ A}$	(see Notes 5 and 6)			1	V
$V_{BE}$ Base-emitter voltage	$V_{CE} = 10 \text{ V}$	$I_C = 1 \text{ A}$	(see Notes 5 and 6)			1.5	V
$h_{fe}$ Small signal forward current transfer ratio	$V_{CE} = 10 \text{ V}$	$I_C = 0.2 \text{ A}$	$f = 1 \text{ kHz}$	25			
$ h_{fe} $ Small signal forward current transfer ratio	$V_{CE} = 10 \text{ V}$	$I_C = 0.2 \text{ A}$	$f = 2 \text{ MHz}$	5			

NOTES: 5. These parameters must be measured using pulse techniques,  $t_p = 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

## resistive-load-switching characteristics at 25°C case temperature

PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
$t_{on}$ Turn on time	$I_C = 1 \text{ A}$	$I_{B(on)} = 0.1 \text{ A}$	$I_{B(off)} = -0.1 \text{ A}$		0.2		$\mu\text{s}$
$t_{off}$ Turn off time	$V_{BE(off)} = -5 \text{ V}$	$R_L = 200 \Omega$	(see Figures 1 and 2)		2		$\mu\text{s}$

† Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

PARAMETER MEASUREMENT INFORMATION

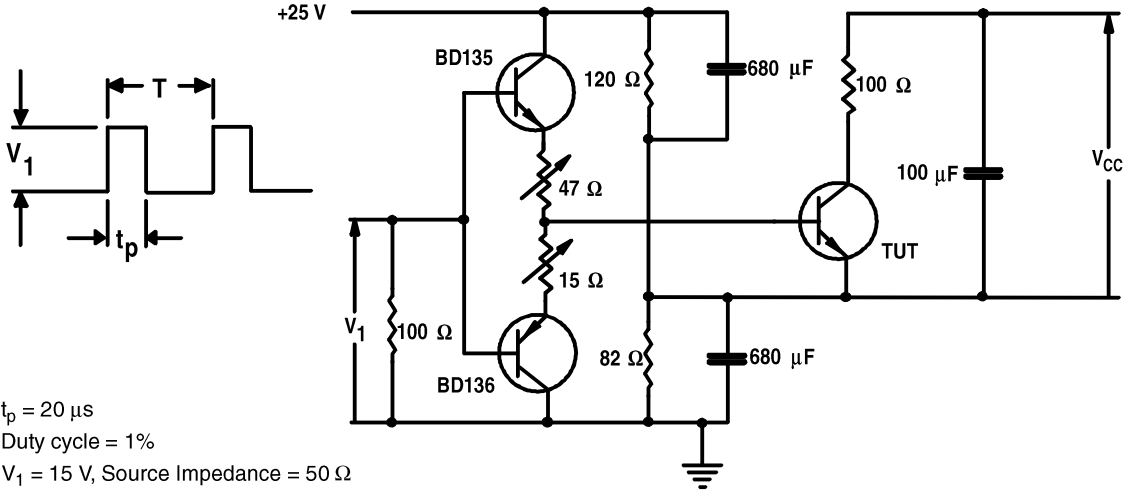


Figure 1. Resistive-Load Switching Test Circuit

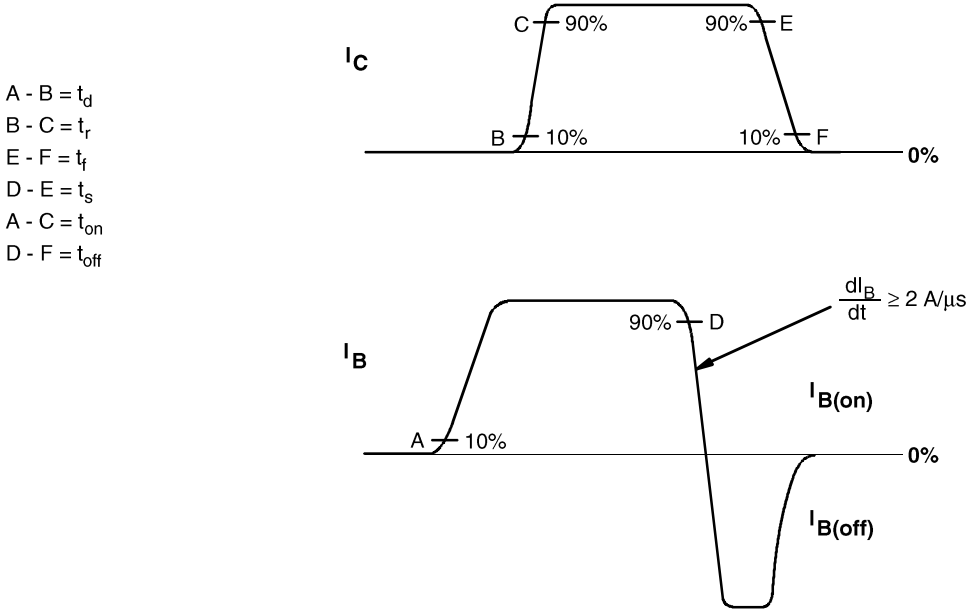


Figure 2. Resistive-Load Switching Waveform

TYPICAL CHARACTERISTICS

TYPICAL DC CURRENT GAIN  
 vs  
 COLLECTOR CURRENT

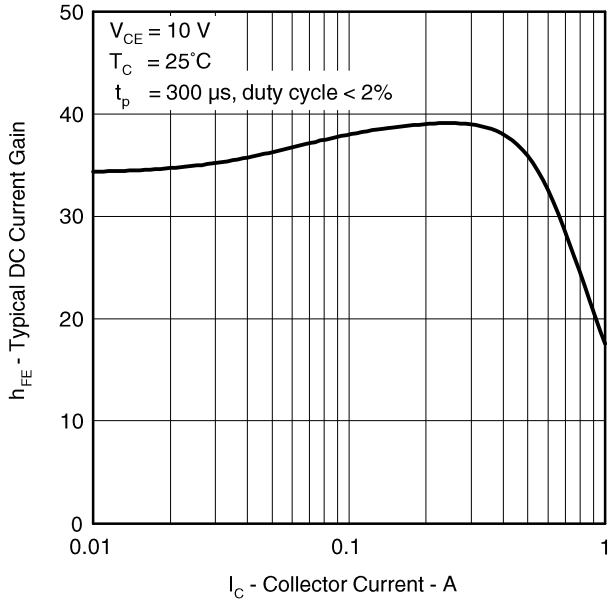


Figure 3.

COLLECTOR-EMITTER SATURATION VOLTAGE  
 vs  
 COLLECTOR CURRENT

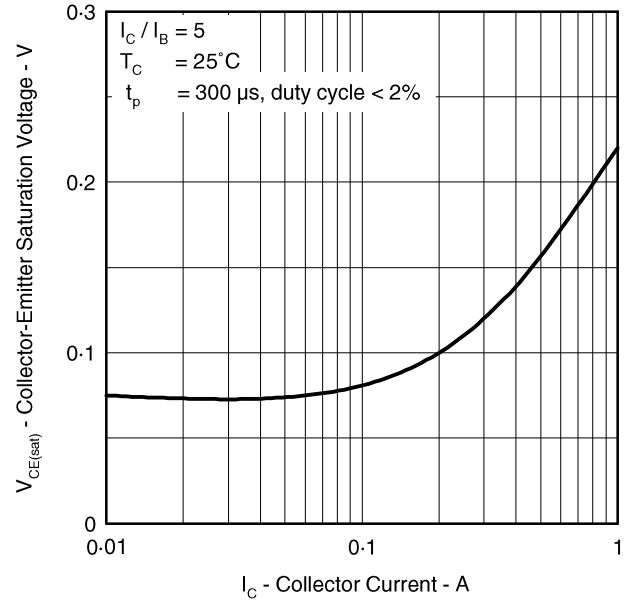


Figure 4.

BASE-EMITTER SATURATION VOLTAGE  
 vs  
 COLLECTOR CURRENT

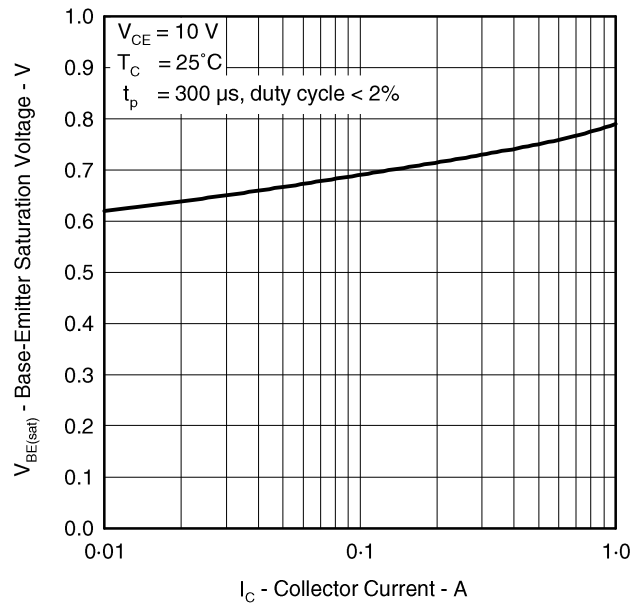


Figure 5.

MAXIMUM SAFE OPERATING REGIONS

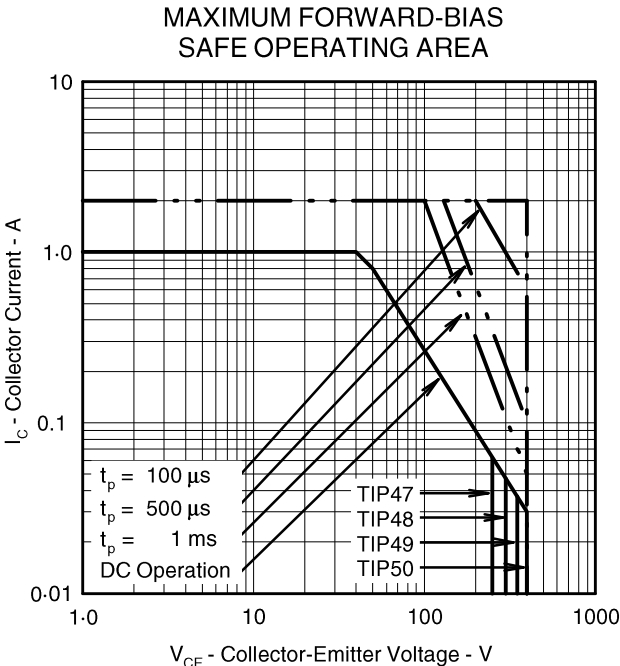


Figure 6.

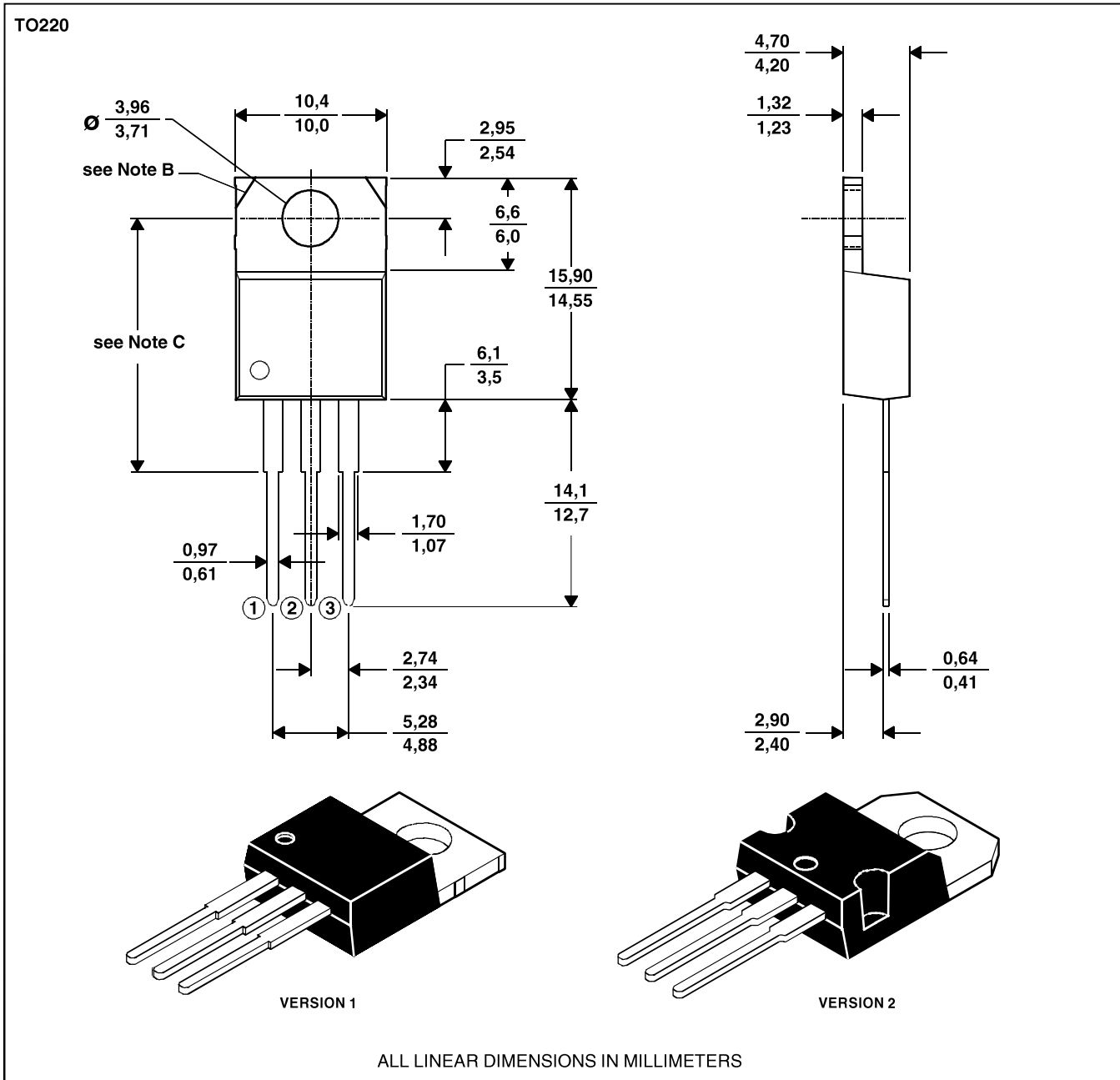
**TIP47, TIP48, TIP49, TIP50**  
**NPN SILICON POWER TRANSISTORS**

**MECHANICAL DATA**

**TO-220**

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



- NOTES: A. The centre pin is in electrical contact with the mounting tab.  
 B. Mounting tab corner profile according to package version.  
 C. Typical fixing hole centre stand off height according to package version.  
 Version 1, 18.0 mm. Version 2, 17.6 mm.